NSN 5961-01-145-3785



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-145-3785 **Inclosure Material:** Glass **Overall Length:** Between 0.120 inches and 0.200 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.055 inches and 0.090 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.94 regulator voltage and 6.06 regulator voltage **Current Rating Per Characteristic:** 65.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Test Data Document:** 10241-a531t300 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) and 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

Mil-std (military Standard):

Mil-prf-19500 spec.

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